

**Features** 

## **Single-Chip Electricity Meter AFE**

### **General Description**

The MAX71020 is a single-chip analog front-end (AFE) for use in high-performance revenue meters. It contains the compute engine (CE) found in Maxim Integrated's fourth-generation meter system-on-chip (SoC) and an improved analog-to-digital converter (ADC), and interfaces to the host controller of choice over a SPI interface.

The MAX71020 comes in a 28-pin TSSOP package.

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#### Ordering Information appears at end of data sheet.

For related parts and recommended products to use with this part, refer to <u>www.maximintegrated.com/MAX71020.related</u>.

#### ♦ 0.1% Accuracy Over 2000:1 Current Range

- Exceeds IEC 62053/ANSI C12.20 Standards
- Two Differential Current Sensor Inputs
- Two Voltage Sensor Inputs
- Selectable Gain of 1 or 8.9 for One Current Input to Support a Shunt
- High-Speed Wh/VARh Pulse Outputs with Programmable Width
- Up to Four Pulse Outputs with Pulse Count
- Four-Quadrant Metering
- Digital Temperature Compensation
- Independent 32-Bit Compute Engine
- ♦ 45Hz to 65Hz Line Frequency Range with Same Calibration
- Phase Compensation (±10°)
- Four Multifunction DIO Pins
- SPI Interface
- ♦ -40°C to +85°C Industrial Temperature Range
- ♦ 28-Pin TSSOP Lead(Pb)-Free Package

### **Typical Operating Circuit**



For pricing, delivery, and ordering information, please contact Maxim Direct at 1-888-629-4642, or visit Maxim Integrated's website at www.maximintegrated.com.

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### **ABSOLUTE MAXIMUM RATINGS**

(All voltages with respect to GNDA.)	Digital Pins
Voltage and Current Supplies and Ground Pins	Inputs (-10mA to +10mA), (-0.5V to +6V)
V3P3SYS, V3P3A0.5V to +4.6V	Outputs (-10mA to +10mA), (-0.5V to (V <sub>3P3SYS</sub> + 0.5V))
GNDD0.1V to +0.1V	Temperature and ESD Stress
Analog Input Pins	Operating Junction Temperature (peak, 100ms)140°C
IAP, IAN, IBP, IBN, VA, VB(-10mA to +10mA),	Operating Junction Temperature (continuous)125°C
(-0.5V to +0.5V)	Storage Temperature Range45°C to +165°C
XIN, XOUT	ESD Stress on All Pins±4kV, HBM
	Lead Temperature (soldering, 10s)
	Soldering Temperature (reflow)+250°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### PACKAGE THERMAL CHARACTERISTICS (Note 1)

TSSOP

Note 1: Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to <u>www.maximintegrated.com/thermal-tutorial</u>.

### ELECTRICAL CHARACTERISTICS

PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNITS
RECOMMENDED OPERATING	CONDITIONS				
V <sub>3P3SYS</sub> and V <sub>3P3A</sub> Supply	Precision metering operation	3.0		3.6	
Voltage	Digital operation (Notes 2, 3)	2.8		3.6	V
Operating Temperature		-40		+85	°C
INPUT LOGIC LEVELS					
Digital High-Level Input Voltage (V <sub>IH</sub> )		2			V
Digital Low-Level Input Voltage (V <sub>IL</sub> )				0.8	V
Input Pullup Current (I <sub>IL</sub> ) RESETZ	$V_{V3P3SYS} = 3.6V, V_{IN} = 0V$	41	78	115	μA
Input Pullup Current (I <sub>IL</sub> ) Other Digital Inputs	$V_{V3P3SYS} = 3.6V, V_{IN} = 0V$	-1	0	+1	μA
Input Pulldown Current (I <sub>IH</sub> ) All Pins	V <sub>IN</sub> = V <sub>V3P3SYS</sub>	-1	0	+1	μA
OUTPUT LOGIC LEVELS					
Digital High-Level Output	$I_{LOAD} = 1mA$	V <sub>V3P3SYS</sub> - 0.4			V
Voltage (V <sub>OH</sub> )	I <sub>LOAD</sub> = 15mA (Note 3)	V <sub>V3P3S</sub> YS - 1.1			v
Digital Low-Level Output	I <sub>LOAD</sub> = 1mA	0		0.4	
Voltage (V <sub>OL</sub> )	I <sub>LOAD</sub> = 15mA (Note 3)	0		0.96	V

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### **ELECTRICAL CHARACTERISTICS (continued)**

PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNITS	
TEMPERATURE MONITOR						
TNOM (Nominal Value at 22°C)	$V_{V3P3A} = 3.3V$		956		LSB	
Temperature Measurement Equation		Temp =	= 0.33 x STE 21.77	EMP +	°C	
	$T_{A} = -40^{\circ}C \text{ to } +85^{\circ}C$	-6		+6		
Temperature Error (Note 4)	$T_A = -20^{\circ}C \text{ to } +60^{\circ}C$	-4.8		+4.8		
Duration of Temperature Measurement After Setting TEMP_START	TEMP_PER = 0		15	60	ms	
SUPPLY CURRENT PERFORM	ANCE SPECIFICATIONS					
V <sub>3P3A</sub> + V <sub>3P3SYS</sub> Current (Note 4)	$V_{V3P3A} = V_{V3P3SYS} = 3.3V, CE_E = 1, ADC_E = 1$		3	4.3	mA	
INTERNAL POWER-FAULT CO	MPARATOR SPECIFICATIONS					
Overall Besponse Time	100mV overdrive, falling	20		200		
	100mV overdrive, rising	8		200	μs	
	3.0V comparator	2.83	2.93	3.03	V	
Falling Threshold	2.8V comparator	2.75	2.81	2.89	V	
	Difference 3.0V and 2.8V comparators	50	136	220	mV	
Hysteresis (Rising Threshold -	3.0V comparator, $T_A = +22^{\circ}C$	17	45	74	mV	
Falling Threshold)	2.8V comparator, $T_A = +22^{\circ}C$	15	42	70		
PLL PERFORMANCE SPECIFIC	CATIONS	·				
PLL Power-Up Settling Time	$V_{V3P3A} = 0$ to 3.3V step, measured from first edge of MCK		75		μs	
DIL EAST Sottling Time	V <sub>V3P3A</sub> = 3.3V, PLL_FAST rise		10			
FLL_FAST Setting Time	V <sub>V3P3A</sub> = 3.3V, PLL_FAST fall				μs	
PLL Lock Frequency at XOUT	V <sub>V3P3A</sub> = 3.3V, MCK frequency error < 1%	7	9.8	13	MHz	
VREF PERFORMANCE SPECIF	ICATIONS					
VREF Output Voltage, VREF (22)	$T_A = +22^{\circ}C$	1.200	1.205	1.210	V	
VREF Power-Supply Sensitivity (DV <sub>REF</sub> /DV <sub>V3P3A</sub> )	$V_{V3P3A} = 3.0V$ to $3.6V$	-1.5		+1.5	mV/V	
VNOM Definition		VNOM TC1(T -	(T) = VREF( 22) + TC2(1	22) + [ - 22) <sup>2</sup>	V	
VNOM Temperature Coefficient TC1		29.32	2 - 1.05 x TF	RIMT	µV/°C	
VNOM Temperature Coefficient TC2		-0.56	- 0.004 x TF	RIMT	µV/°C²	
VREF(T) Deviation from VNOM(T): VREF(T) - VNOM(T) 10 <sup>6</sup> VNOM(T) 62	(Note 4)	-40		+40	ppm/°C	

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### **ELECTRICAL CHARACTERISTICS (continued)**

PARAMETER	CON	DITIONS	MIN	ТҮР	MAX	UNITS	
ADC CONVERTER PERFORMA	NCE SPECIFICATIONS						
Recommended Input Range (with Respect to GNDA)	VA, VB, IBP, IBN	VA, VB, IBP, IBN			+250	mVpk	
Recommended Input Range	IAP, IAN: preamplifier en	abled	-27.78		+27.78	m\/nk	
(with Respect to GNDA)	IAP, IAN: preamplifier dis	abled	-250		+250	Пітурк	
Input Impedance, No Preamplifier	$f_{IN} = 65Hz$		50		100	kΩ	
ADC Gain Error vs Percentage Power-Supply Variation							
$\frac{10^{6} \Delta \text{Nout}_{\text{PK}} 357 \text{nV}/\text{V}_{\text{IN}}}{100 \Delta \text{V} 3\text{P3A}/3.3}$	V <sub>IN</sub> = 200mV peak, 65Hz	; V <sub>V3P3A</sub> = 3.0V, 3.6V			81	ppm/%	
Input Offset	IAP = IAN = GNDA		-10		+10	mV	
Total Harmonic Distortion at 250mVpk	V <sub>IN</sub> = 55Hz, 250mVpk, 64 Blackman Harris Window	4kpts FFT,		-85		dB	
Total Harmonic Distortion at 20mVpk	V <sub>IN</sub> = 55Hz, 20mVpk, 64ł Blackman Harris Window	kpts FFT,		-90		dB	
		FIRLEN = 15		120.46			
LSB Size (LSB Values Do Not Include the 9-Bit Left Shift at the CF Input)	V <sub>IN</sub> = 55Hz, 20mVpk, 64kpts FFT, Blackman- Harris window, 10MHz ADC clock	FIRLEN = 14		146.20			
		FIRLEN = 13		179.82		nV	
		FIRLEN = 12		224.59			
		FIRLEN = 11		285.54			
		FIRLEN = 10		370.71			
		FIRLEN = 15		±2621440			
		FIRLEN = 14		±2160000			
Digital Full Scale	$V_{IN} = 55Hz$ , 400mVpk,	FIRLEN = 13		±1756160			
	10MHz ADC clock	FIRLEN = 12		±1406080			
		FIRLEN = 11		±1105920			
		FIRLEN = 10		±851840			
PREAMPLIFIER PERFORMANC	E SPECIFICATIONS		1				
Differential Gain, (V <sub>IN</sub> = 28mV Differential)	$T_A = +25^{\circ}C. V_{V2P3A} = 3.$	3V. preamplifier enabled		8.9		V/V	
Differential Gain (V <sub>IN</sub> = 15mV Differential)	$T_A = +25$ C, $V_{V3}P_{3A} = 0.5V$ , preampliner enabled						
Gain Variation vs. V <sub>3P3A</sub> (V <sub>IN</sub> = 28mV Differential)	V <sub>V3P3A</sub> = 3.0V, 3.6V		-72		ppm/%		
Gain Variation vs. Temperature (V <sub>IN</sub> = 28mV Differential)	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		-45		ppm/°C		
Phase Shift (V <sub>IN</sub> = 28mV Differential)	$T_A = +25^{\circ}C, V_{V3P3A} = 3.$	0		8	milli- degree		
Preamplifier Input Current (IIAP)	Preamplifier enabled. IAE	DC0 = IADC1 = GNDA	9	15	20	μA	
Preamplifier Input Current (I <sub>IAN</sub> )		-	-	-	· ·		

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### **ELECTRICAL CHARACTERISTICS (continued)**

PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNITS
Preamplifier and ADC Total Harmonic (V <sub>IN</sub> = 28mV Differential)	$T_A = +25^{\circ}C; V_{V3P3A} = 3.3V, PRE_E = 1$		-80		dB
Preamplifier and ADC Total Harmonic Distortion (V <sub>IN</sub> = 15mV Differential)	$T_A = +25^{\circ}C; V_{V3P3A} = 3.3V, PRE_E = 1$		-85		dB
SPI SLAVE TIMING SPECIFICA	TIONS				
SPI Setup Time	SPI_DI to SPI_CK rise	10			ns
SPI Hold Time	SPI_CLK rise to SPI_DI	10			ns
SPI Output Delay	SPI_CLK fall to SPI_D0			40	ns
SPI Recovery Time	SPI_CSZ fall to SPI_CLK	10			ns
SPI Removal Time	SPI_CLK to SPI_CSZ rise	15			ns
SPI Clock High		40			ns
SPI Clock Low		40			ns
SPI Clock Frequency				10	MHz
SPI Transaction Space (SPI_CSZ Rise to SPI_CSZ Fall)		1			μs
RESETZ TIMING	·				
Depart Dulas Width	Following power-on	1			ms
Reset Puise Width	At all other times	5			μs
Reset Pulse Rise Time	(Note 4)			1	μs
VOLTAGE MONITOR					
Nominal Value at +22°C (VNOM)	$V_{V3P3A} = 3.3V$		130		LSB
Voltage Measurement Equation		V <sub>V3P3SYS</sub> (VSENSE STE	s(CALC) = 3 – 130) x 0. EMP x 242µ	3.29V + 025V + V	
Voltage Error					
$100 \times \left( \frac{\ddot{u}\ddot{u}\ddot{u}\ddot{u}}{V_{\ddot{u}\ddot{u}\ddot{u}}} - 1 \right)$		-4		+4	%

**Note 2:** V<sub>3P3SYS</sub> and V<sub>3P3A</sub> must be connected together. **Note 3:** GNDA and GNDD must be connected together.

**Note 4:** Guaranteed by design, not production tested.

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NAME	FROM	то	FUNCTION	VALUE	UNITS
C1	V <sub>3P3A</sub>	GNDA	Bypass capacitor for 3.3V supply	≥ 0.1 ±20%	μF
CSYS	V <sub>3P3SYS</sub>	GNDD	Bypass capacitor for V <sub>3P3SYS</sub>	≥ 1.0 ±30%	μF
C1P8	V <sub>DD</sub>	GNDD	Bypass capacitor for V1P8 regulator	0.1 ±20%	μF
XTAL	XIN	XOUT	At cut crystal specified for 18pF load	9.8304	MHz
CXS	XIN	GNDA	Load capacitor values for crystal depend on crystal specifications and board parasitics.	32 ±10%	pF
CXL	XOUT	GNDA	capacitance and include an allowance for chip capacitance.	32 ±10%	pF

### **RECOMMENDED EXTERNAL COMPONENTS**

### **Pin Configuration**



# **Single-Chip Electricity Meter AFE**

### **Pin Description**

(Pin types: P = Power, O = Output, I = Input, I/O = Input/Output. The circuit number denotes the equivalent circuit, as specified under Figure 1).

PIN	NAME	TYPE	CIRCUIT	DESCRIPTION
POWER AND GRO			1	
2	GNDA	Р		Analog Ground. GNDA should be connected directly to the ground plane.
3	V <sub>3P3A</sub>	Р	_	Analog Power Supply. A 3.3V power supply should be connected to $V_{3P3A}$ . $V_{3P3A}$ must be the same voltage as $V_{3P3SYS}$ .
12	GNDD	Р		Digital Ground. GNDD should be connected directly to the ground plane.
23	V <sub>DD</sub>	0	_	Output of the 1.8V Regulator. A 0.1 $\mu$ F bypass capacitor to ground should be connected to this pin.
24	V <sub>3P3SYS</sub>	Р	_	System 3.3V Supply. $V_{3P3SYS}$ should be connected to a 3.3V power supply.
ANALOG PINS				
7, 6	IAP, IAN		_	Differential or Single-Ended Line Current-Sense Inputs. These pins are
5, 4	IBP, IBN	I	6	to the outputs to the internal ADC. Typically, these pins are connected to the outputs of current sensors. <b>Unused pins must be tied to GNDA</b> .
1, 28	VA, VB	I	6	Line Voltage Sense Inputs. VA/VB are voltage inputs to the internal ADC. Typically, the pins are connected to the outputs of resistor- dividers. <b>Unused pins must be tied to GNDA</b> .
25	XIN	I	0	Crystal Inputs. A 9.8304MHz crystal should be connected to XIN and
26	XOUT	0	Ö	XOUT.
DIGITAL PINS				
22	DIO0/WPULSE			Multiple-Use Pins, Configurable as DIO, Alternative functions with
21	DIO1/VPULSE	1/0	3.4	proper selection of associated registers are:
20	DIO2/XPULSE	1/0	0, 4	DIO0 = WPULSE
11	DIO3/YPULSE			DIOT = VFOLSE
8, 27	TEST, TESTO		3	Connect to GNDD
9	RESETZ	I	3	Active-Low Reset
13	SPI_CSZ		3	
14	SPI_DO	0	4	SPI Interface
15	SPI_DI	I	3	Similarace
16	SPI_CLK		3	
19	INTZ	0	4	Active-Low Interrupt Request
OTHER PIN				
10	V <sub>PP</sub>	I		Connect to GNDD



# **Single-Chip Electricity Meter AFE**

Figure 1. I/O Equivalent Circuits

# **Single-Chip Electricity Meter AFE**

**Functional Diagram** 



## **Single-Chip Electricity Meter AFE**

### **Hardware Description**

#### **Hardware Overview**

The MAX71020 energy meter analog front-end (AFE) integrates all primary functional blocks required to implement a solid-state residential electricity meter. Included on the chip are:

- An analog front-end (AFE) featuring a 22-bit secondorder sigma-delta ADC
- An independent 32-bit digital computation engine (CE) to implement DSP functions
- A precision voltage reference (VREF)
- A temperature sensor for digital temperature sensing and compensation
- Four I/O pins
- A zero-crossing detector with interrupt output
- Resistive shunt and current transformers
   are supported
- A SPI slave for connection to a host controller

In a typical application, the 32-bit compute engine (CE) of the MAX71020 sequentially processes the samples from the voltage inputs on analog input pins and performs calculations to measure active energy (Wh) and reactive energy (VARh), as well as A<sup>2</sup>h, and V<sup>2</sup>h for four-quadrant metering. These measurements are then accessed by the host controller.

In addition to the temperature-trimmed ultra-precision voltage reference, the on-chip digital temperature compensation mechanism includes a temperature sensor and associated controls for correction of unwanted temperature effects on measurement, e.g., to meet the requirements of ANSI and IEC standards.

Temperature-dependent external components such as crystal oscillator, resistive shunts, current transformers (CTs) and their corresponding signal conditioning circuits can be characterized and their correction factors can be programmed to produce electricity meters with exceptional accuracy over the industrial temperature range.

Communications with the host is conducted over a SPI interface. The communications protocol between the host and the MAX71020 provides a redundant information transfer ensuring the correctness of commands transferred from the host to the AFE, and of data transferred from the AFE to the host.

In addition, the MAX71020 has one pin dedicated as an interrupt output to the host. This pin notifies the host of asynchronous events.

#### Analog Section

#### Signal Input Pins

The MAX71020 has four analog inputs: two single-ended inputs for voltage measurement, and two differential inputs for current measurement.

The IAP, IAN, IBP, and IBN pins are current sensor inputs. The differential inputs feature preamplifiers with a selectable gain of 1 or 9, and are intended for direct connection to a shunt resistor sensor or a current transformer (CT).

The voltage inputs in the MAX71020 are single-ended, and are intended for sensing the line voltage via resistive dividers. These single-ended inputs are referenced to the GNDA pin.

All analog signal input pins measure voltage. In the case of shunt current sensors, currents are sensed as a voltage drop in the shunt resistor sensor. In the case of Current Transformers (CT), the current is measured as a voltage across a burden resistor that is connected to the secondary winding of the CT. Meanwhile, line voltages are sensed through resistive voltage-dividers.

Some versions of the device implement a preamplifier with a fixed gain of 8.9 to enhance performance when using sensors with a low-amplitude output (for example, current shunts). When using a device with the preamplifier enabled, the input signal amplitude cannot be greater than 27.78mV peak.

#### Input Multiplexer

The input multiplexer sequentially applies the input signals from the analog input pins to the input of the ADC. One complete sampling sequence is called a multiplexer frame.

The IBP-IBN differential input may be used to sense the neutral current, and VB may be optionally used to sense a second voltage channel. This configuration implies that the multiplexer applies a total of four inputs to the ADC. For this configuration, the multiplexer sequence is as shown in <u>Figure 2</u>. In this configuration IAP-IAN, IBP-IBN, VA and VB are sampled. The physical current sensor for the neutral current measurement and the voltage sensor for VB may be omitted if not required.

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For a standard single-phase application with tamper sensor in the neutral path, two current inputs are configured for differential mode, using the pin pairs IAP-IAN and IBP-IBN. The MAX71020 uses two locally connected current sensors via IAP-IAN and IBP-IBN for this configuration. The VA pin is typically connected to the phase voltage via resistor-dividers.

The MAX71020 adds the ability to sample a second phase voltage (applied at the VB pin), which makes it suitable for meters with two voltage and two current sensors, such as meters implementing Equation 2 for dual-phase operation ( $P = VA \times IA + VB \times IB$ ).

Table 1 summarizes the AFE input configuration.

#### **Delay Compensation**

When measuring the energy of a phase (i.e., Wh and VARh) in a service, the voltage and current for that phase must be sampled at the same instant. Otherwise, the phase difference,  $\phi$ , introduces errors.

$$\phi = \frac{t_{delay}}{T} \times 360^{\circ} = t_{delay} \times f \times 360^{\circ}$$

where f is the frequency of the input signal, T = 1/f and  $t_{delay}$  is the sampling delay between current and voltage.

#### Table 1. ADC Input Configuration

PIN	COMMENT			
IAP	The ADC regults are stored in register IA			
IAN	The ADC results are stored in register IA.			
IBP	The ADC requite are stored in register IP			
IBN	The ADC results are stored in register 1b.			
VA	The ADC result is stored in register VA.			
VB	The ADC result is stored in register VB.			

Traditionally, sampling is accomplished by using two ADCs per phase (one for voltage and the other one for current) controlled to sample simultaneously. Maxim Integrated's Single Converter Technology®, however, exploits the 32-bit signal processing capability of its CE to implement "constant delay" allpass filters. The allpass filter corrects for the conversion time difference between the voltage and the corresponding current samples that are obtained with a single multiplexed ADC.

The constant delay allpass filter provides a broadband delay  $360^{\circ} - \theta$ , which is precisely matched to the difference in sample time between the voltage and the current of a given phase. This digital filter does not affect the amplitude of the signal, but provides a precisely controlled phase response.

The ADC multiplexer samples the current first, immediately followed by sampling of the corresponding phase voltage, thus the voltage is delayed by a phase angle  $\phi$  relative to the current. The delay compensation implemented in the CE aligns the voltage samples with their corresponding current samples by first delaying the current samples by one full sample interval (i.e., 360°), then routing the voltage samples through the allpass filter, thus delaying the voltage samples by 360° -  $\theta$ , resulting in the residual phase error between the current and its corresponding voltage of  $\theta - \phi$ . The residual phase error is negligible, and is typically less than  $\pm 0.0015^{\circ}$  at 100Hz, thus it does not contribute to errors in the energy measurements.

#### ADC Preamplifier

The ADC preamplifier is a low-noise differential amplifier with a fixed gain of 8.9 available on the IAP and IAN current-sensor input pins. It is provided only in versions of the MAX71020 AFE configured for use with current shunts.



Figure 2. States in a Multiplexer Frame

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#### Maxim Integrated

## **Single-Chip Electricity Meter AFE**

#### Analog-to-Digital Converter (ADC)

A single second-order delta-sigma ADC digitizes the voltage and current inputs to the device. The resolution of the ADC is dependent on several factors.

Initiation of each ADC conversion is automatically controlled by logic internal to the MAX71020. At the end of each ADC conversion, the FIR filter output data is stored into the register determined by the multiplexer selection. FIR data is stored LSB justified, but shifted left 9 bits.

#### FIR Filter

The finite impulse response filter is an integral part of the ADC and it is optimized for use with the multiplexer. The purpose of the FIR filter is to decimate the ADC output to the desired resolution. At the end of each ADC conversion, the output data is stored into the register determined by the multiplexer selection.

#### Voltage References

A bandgap circuit provides the reference voltage (VREF) to the ADC. Since the VREF bandgap amplifier is chopper stabilized, the DC offset voltage, which is the most significant long-term drift mechanism in the voltage reference (VREF), is automatically removed by the chopper circuit.

#### **Digital Computation Engine (CE)**

The CE, a dedicated 32-bit signal processor, performs the precision computations necessary to accurately measure energy. The CE calculations and processes include:

- Multiplication of each current sample with its associated voltage sample to obtain the energy per sample (when multiplied with the constant sample time)
- Frequency-insensitive delay cancellation on all four channels (to compensate for the delay between samples caused by the multiplexing scheme)
- 90° phase shifter (for VAR calculations)
- Pulse generation
- Monitoring of the input signal frequency (for frequency and phase information)

- Monitoring of the input signal amplitude (for sag detection)
- Scaling of the processed samples based on calibration coefficients
- Scaling of samples based on temperature compensation information
- Gain and phase compensation

#### Meter Equations

The MAX71020 provides hardware assistance to the CE in order to support various meter equations. This assistance is controlled through registers that are controlled by the CE code image. The CE firmware implements the equations listed in Table 2 or a subset thereof.

#### **Pulse Generators**

The MAX71020 provides up to four pulse generators, VPULSE, WPULSE, XPULSE, and YPULSE, as well as hardware support for the VPULSE and WPULSE pulse generators. The pulse generators are used to output CE status indicators and energy usage. See <u>Table 3</u>.

The polarity of the pulses may be inverted with control bit PLS\_INV. When this bit is set, the pulses are active-high, rather than the more usual active-low. PLS\_INV inverts all four pulse outputs.

The function of each pulse generator is determined by the CE code. Standard configurations of the MAX71020 provide a mains zero-crossing indication on XPULSE and voltage sag detection on YPULSE.

A common use of the zero-crossing pulses is to generate interrupts in order to drive RTC software in places where the mains frequency is sufficiently accurate to do so and also to adjust for crystal aging. Zero-crossing can also be used to control PLC modems or cut-off relays. A common use for the SAG pulse is to generate an interrupt that alerts the host controller when mains power is about to fail, so that the host controller can store accumulated energy and other data to EEPROM before the board supply voltage drops below safe levels.

Table 2. Ir	າputs 🤅	Selected	in M	ultiplexer	Cycles
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FOU	DESCRIPTION	Wh AND VARh FORMULA			
EQU	DESCRIPTION	ELEMENT 0	ELEMENT 1		
0	1 element, 2W, $1\phi$ with neutral current sense	VA · IA	VA · IB		
1	1 element, 3-W, 1φ	VA(IA-IB)/2	VA · IB/2		
2	2 element, 3-W	VA · IA	VB · IB		

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### **Table 3. Pulse Output Function Assignments**

OUTPUT	FUNCTION					
XPULSE	Pulse output on each zero crossing on voltage input					
YPULSE	Pulse output when voltage sag detected					
VPULSE	Pulse output when programmed VARh consumption has occurred					
WPULSE	Pulse output when programmed Wh consumption has occurred					

#### XPULSE and YPULSE

Pulses generated by the CE may be exported to the XPULSE and YPULSE pulse output pins. Pins D2 and D3 are used for these pulses, respectively. The XPULSE and YPULSE outputs can be updated once on each pass of the CE code. See the <u>CE Interface Description</u> section for details.

#### VPULSE and WPULSE

By default, WPULSE and VPULSE are negative pulses (i.e., low level pulses, designed to sink current through an LED). PLS\_MAXWIDTH[7:0] determines the maximum negative pulse width  $T_{MAX}$  in units of 2.458MHz clock cycles based on the pulse interval  $T_I$  according to the formula:

#### $T_{MAX} = (2 \times PLS_MAXWIDTH[7:0] + 1) \times T_I$

 $T_I$  is based on an internal value that determines the pulse interval and the ADC clock, both of which are determined by the particular characteristics of the CE code. In the MAX71020, the default value for  $T_I$  is 65.772µs, but this value may change in customized versions of this device.

If PLS\_MAXWIDTH = 255 no pulse-width checking is performed, and the pulses default to 50% duty cycle.  $T_{MAX}$ is typically programmed to 10ms ( $T_{MAX} = 76$ ), which works well with most calibration systems.

The polarity of the pulses may be inverted with the control bit PLS\_INV. When PLS\_INV is set, the pulses are active-high. The default value for PLS\_INV is zero, which selects active-low pulses.

The WPULSE and VPULSE pulse generator outputs are available on pins D0/WPULSE and D1/VPULSE, respectively.

**Temperature Sensor** The MAX71020 includes an on-chip temperature sensor for determining the temperature of its bandgap reference. The primary use of the temperature data is to determine the magnitude of compensation required to offset the thermal drift in the system for the compensation of current, voltage, and energy measurement. See the *Metrology Temperature Compensation* section.

The temperature sensor is awakened on command from the host controller by setting the TEMP\_START control bit. The host controller must wait for the TEMP\_START bit to clear before reading STEMP[15:0] and before setting the TEMP\_START bit once again.

The result of the temperature measurement can be read from the STEMP[15:0] register. The 16-bit value is in two's complement form and ranges from -1024 to +1023 (decimal). The sensed temperature can be computed from the 16-bit STEMP[15:0] reading using the following formula:

$$Temp (^{\circ}C) = 0.33 \times STEMP + 21.77$$

An additional register, VSENSE[7:0], senses the level of the supply voltage. <u>Table 4</u> shows the registers used for temperature measurement.

#### Digital I/O

On reset or power-up, all DIO pins are configured as high impedance. DIO pins can be configured independently by the host controller by manipulating the D0, D1, D2, and D3 bit fields.

# **Single-Chip Electricity Meter AFE**

NAME	RST	WK	DIR	DESCRIPTION		
				Sets the period betwe	een temperature measurements.	
				TEMP_PER	TIME	
				0	Manual updates (see TEMP_START description)	
				1	Every accumulation cycle	
				2	Continuous	
				3	No updates	
TEMP_START	0		R/W	TEMP_PER[1:0] must be zero in order for TEMP_START to function. If TEMP_ PER[1:0] = 0, then setting TEMP_START starts a temperature measurement. Hardware clears TEMP_START when the temperature measurement is complete. The host controller must wait for TEMP_START to clear before reading STEMP[10:0] and before setting TEMP_START again.		
STEMP[15:0]		_	R	The result of the temperature measurement.		
VSENSE[7:0]			R	The result of the temperature measurement (see the formula listed in the <i>Electrical Characteristics</i> table).		

### **Table 4. Temperature Measurement Registers**

#### SPI Slave Port

The slave SPI port communicates directly with the host controller and allows it to read and write the device control registers. The interface to the slave port consists of the SPI\_CSZ, SPI\_CLK, SPI\_DI, and SPI\_DO pins. The host can also reset the MAX71020 through the SPI port by writing a data pattern to the RESET register (see Table 7).

#### SPI Transactions

SPI transactions are configured to provide immunity to electrical noise through redundancy in the command segment and error checking in the data field. The MAX71020 SPI transaction is exactly 64 bits; transactions of any other length are rejected. Each SPI transaction has the following fields (see Table 5):

- A 24-bit setting packet, consisting of
- 11-bit address, MSB first
  - 1-bit direction (1 means read)
  - 11-bit inverted address, MSB first
  - 1-bit inverted direction
- An 8-bit status, consisting of the following bits concerning the last transaction, starting from bit 7:
  - Parity of the status byte (0 or 1 could be correct)
  - FIFO overflow status bit (1 means error)
  - FIFO underrun status bit (1 means error)
  - Read or write data parity (0 or 1 could be correct) (never both read and write; address is not included in the parity)

- Address or direction mismatch error bit (1 means error) (1: error, 0 : no error)
- A bit indicating whether or not the bit count was exactly 64 (1 means error)
- Out of bounds address, most likely due to SPI safe bit or the memory manager (1 means error)
- A 32-bit packet of data, MSB first

If extra clocks are provided at the end during a read, all zero is output and the status continues to be updated, signaling an error. If extra clocks are provided at the end during a write, the write is aborted and the status is updated to signal an error.

- None of the fields above are optional.
- If an error is detected during the address or direction phase, no action is taken.
- SPI\_DO is high-Z while SPI\_CSZ is high.
- SPI safe mode is supported, and SPI is not locked out of this bit during SPI safe.

A typical SPI transaction is as follows. While SPI\_CSZ is high, the port is held in an initialized/reset state. During this state, SPI\_DO is held in high-Z state and all transitions on SPI\_CLK and SPI\_DI are ignored. When SPI\_CSZ falls, the port begins the transaction on the first rising edge of SPI\_CLK. A transaction consists of the fields shown in Table 5.

# **Single-Chip Electricity Meter AFE**

24-E	SIT SI	ETTING FIELD		8-BIT STATUS								32-BIT DATA
Address	Dir	Inv Address	Inv Dir		St	atus from Pr	evious	Transaction	: status[7:	0]		Data
addr[10:0]	RD	addr_b[10:0]	RD_b	Status Parity	FIFO OverRun	FIFO UnderRun	Data Parity	Setting Mismatch	Reserved	Bad CK Cnt	Bad Address	data[31:0]
SERIAL READ       11-BIT ADDRESS       RD       STATUS BYTE       DATA [ADDR]         (FROM HOST) SPL_CSZ       0       10       11       22       23       24       31       32       47       48         (FROM HOST) SPL_CLK       0       10       11       22       23       24       31       32       47       48         (FROM HOST) SPL_CLK       0       10       11       22       23       24       31       32       47       48         (FROM HOST) SPL_CLK       0       10       11       10       11       10       11       10       11       10       11       10       11       10       11       10       11       10       11       10       11       10       11       10       11       10       11       10       11       10       11       10       10       10       11       10       10       10       10       10       11       10       11       10												
SERIAL (FROM HOST) S (FROM HOST) S (FROM HOST) (FROM AM48)	_ WRITE SPI_CSZ SPI_CLK SPI_DI SPI_DO		DDRESS	RD 10 11 			STATUS B'	YTE 31 32 (D31)(I (D31)(I 	47 	48 48 5 X D 15 X D 1-		63 (D1)(D0)(X

### Table 5. SPI Transaction (64 Bits)

Figure 3. SPI Slave Port—Typical READ and WRITE operations

Note that the status byte indicates the status of the previous SPI transaction except for the status byte parity.

#### SPI Safe Mode

Sometimes it is desirable to prevent the SPI interface from writing to arbitrary registers and possibly disturbing the CE operation. For this reason, the SPI\_SAFE mode was created. In this mode, all SPI writes are disabled except to the word containing the SPI\_SAFE bit. This affords the host one more layer of protection from inadvertent writes.

### **Functional Description**

#### Theory of Operation

The energy delivered by a power source into a load can be expressed as:

$$E = \int_{0}^{t} V(t)I(t)dt$$

Assuming phase angles are constant, the following formulae apply:

 $P = Real Energy [Wh] = V \times A \times \cos \phi \times t$ 

Q = Reactive Energy [VARh] = V x A x sin 
$$\phi$$
 x t

S = Apparent Energy [VAh] = 
$$\sqrt{P^2 + Q^2}$$

For a practical meter, not only voltage and current amplitudes, but also phase angles and harmonic content may constantly change. Thus, simple RMS measurements are inherently inaccurate. A modern solid-state electricity meter IC such as the MAX71020 functions by emulating the integral operation above, i.e., it processes current and voltage samples through an ADC at a constant frequency. As long as the ADC resolution is high enough and the sample frequency is beyond the harmonic range of interest, the current and voltage samples, multiplied with the time period of sampling yield an accurate quantity for the momentary energy. Summing the instantaneous energy quantities over time provides very accurate results for accumulated energy.





Figure 4. Voltage, Current, Momentary and Accumulated Energy

Figure 4 shows the shapes of V(t), I(t), the instantaneous power and the accumulated energy resulting from 50 samples of the voltage and current signals over a period of 20ms. The application of 240V AC and 100A results in an accumulation of 480Ws (= 0.133Wh) over the 20ms period, as indicated by the accumulated power curve. The described sampling method works reliably, even in the presence of dynamic phase shift and harmonic distortion. After a sufficient number (typically 2520) of multiplexer frames have been collected, the MAX71020 issues an interrupt to the host using the INTZ pin, signalling that new energy values are available.

#### Fault and Reset Behavior Events at Power-Down

Power fault detection is performed by internal comparators that monitor the voltage at the V<sub>3P3A</sub> pin and also monitor the internally generated V<sub>DD</sub> pin voltage (1.8V DC). V<sub>3P3SYS</sub> and V<sub>3P3A</sub> must be connected together at the PCB level so that the comparators, which are internally connected only to the V<sub>3P3A</sub> pin, are able to simultaneously monitor the common V<sub>3P3SYS</sub> and V<sub>3P3A</sub> voltage. The following discussion assumes that V<sub>3P3A</sub> and V<sub>3P3SYS</sub> are connected together at the PCB level.

During a power failure, as  $V_{3P3A}$  falls, two thresholds are detected. The first threshold, at 3.0V, warns the host controller that the analog modules are no longer accurate. The second threshold, at 2.8V, warns the host controller that a serious reduction in supply voltage has occurred and that the reliability of OTP reads may be affected.

#### **Reset Sequence**

The MAX71020 does not provide automatic reset generation. The reset needs to be generated by the host controller or by external circuitry connected to the RESETZ pin. When the MAX71020 receives a reset signal, either from the RESETZ pin or from the SPI (using a write to the RESET register at address 0x322), it asynchronously halts what it was doing. It then clears the RAM and invokes the Load Engine (LE). The LE initializes RAM and hardware control registers from the CE code image that is stored in OTP memory. Only RAM cells and hardware registers that need not change dynamically are loaded. All other RAM cells and registers have to be loaded by the host controller. The LE automatically refreshes the values of the registers it is tasked with loading during the operation of the MAX71020. This refresh happens in increments of one register at a time and at a rate of one register per second.

An errant reset can occur during EMI events. If this happens, the host controller is notified. This is accomplished by the holding the INTZ pin low until the host clears the event (the F\_RESET bit in the M\_STAT register is set to indicate that a reset has occurred).

#### **Applications Information**

#### **Sensor Connection**

Figure 5 to Figure 8 show voltage-sensing resistive dividers, current-sensing current transformers (CTs) and current-sensing resistive shunts and their proper connection to the voltage and current inputs of the MAX71020. All input signals to the MAX71020 sensor inputs are voltage signals providing a scaled representation of either a sensed voltage or current.

### Table 6. VSTAT[1:0]

VSTAT[1:0]	DESCRIPTION
00	System Power-OK. $V_{V3P3A} > 3.0V$ . Analog modules are functional and accurate.
01	System Power is low. 2.8V < V <sub>V3P3A</sub> < 3.0V. Analog modules not accurate.
11	System power below 2.8V. Ability to monitor power is about to fail.

# **Single-Chip Electricity Meter AFE**



Figure 5. Resistive Voltage-Divider (Voltage Sensing)



Figure 6. CT With Single-Ended Input Connection (Current Sensing)



Figure 7. CT With Differential Input Connection (Current Sensing)



Figure 8. Differential Resistive Shunt Connections (Current Sensing)

## **Single-Chip Electricity Meter AFE**

**Connecting the MAX71020** 

The analog input pins of the MAX71020 are designed for sensors with low source impedance. RC filters with resistance or capacitance values higher than those implemented in the demo boards must not be used. Refer to the demo board schematics for complete sensor input circuits and corresponding component values. Maxim Integrated does not recommend the use of ferrites directly at the analog signal input.

Figure 9 shows a typical MAX71020 configuration. The IAP-IAN current channel may be directly connected to either a shunt resistor or a CT, while the IBP-IBN channel is connected to a CT and is therefore isolated. This configuration implements a single-phase measurement with tamper-detection using one current sensor to measure the neutral current. This configuration can also be used to create a split phase meter (e.g., ANSI Form 2S).



Figure 9. Connecting the MAX71020

### **Single-Chip Electricity Meter AFE**

Host connections include the INTZ pin, the RESETZ pin, and an optional YPULSE pin. In the host controller, the DIO pin connected to INTZ should generate an interrupt. This interrupt signals to the host that an accumulation cycle has been completed.

#### Metrology Temperature Compensation Voltage Reference Precision

Since the VREF bandgap amplifier is chopper-stabilized the DC offset voltage, which is the most significant longterm drift mechanism in the voltage references, is automatically removed by the chopper circuit. Maxim Integrated trims the VREF voltage reference during the device manufacturing process to ensure the best possible accuracy.

The reference voltage (VREF) is trimmed to a target value of 1.205V nominal. During this trimming process, the TRIMT[7:0] value is stored in nonvolatile fuses. TRIMT[7:0] is trimmed to a value that results in minimum VREF variation with temperature.

The TRIMT[7:0] value can be read by the host controller during initialization to calculate parabolic temperature compensation coefficients suitable for each individual device. The achievable temperature coefficient for VREF is ±40ppm/°C.

Considering the factory calibration temperature of VREF to be  $+22^{\circ}$ C and the industrial temperature range (-40°C to +85°C), the VREF error at temperature extremes can be calculated as:

 $(85^{\circ}C - 22^{\circ}C) \times 40$ ppm/°C = +2520ppm = ±0.252% and

#### $(-40^{\circ}C - 22^{\circ}C) \times 40$ ppm/°C = +2480ppm = -0.248%

The above calculation implies that both the voltage and the current measurements are individually subject to a theoretical maximum error of approximately  $\pm 0.25\%$ . When the voltage sample and current sample are multiplied together to obtain the energy per multiplexer frame, the voltage error and current error combine resulting in approximately  $\pm 0.5\%$  maximum energy measurement error. However, this theoretical  $\pm 0.5\%$  error considers only the voltage reference (VREF) as an error source. In practice, other error sources are the current sensors (shunts or CTs) and their corresponding signal conditioning circuits, and the resistor voltage-divider used to measure the voltage. The MAX71020 0.5\% grade devices should be used in class 1% designs, allowing sufficient margin for the other error sources in the system.

#### Mechanism

The MAX71020's CE code performs temperature compensation for the metrology when the EXT\_TEMP bit in the CECONFIG register is 0 (default setting). In the internal temperature compensation mode, the CE controls the GAIN\_ADJ0, GAIN\_ADJ1, and GAIN\_ADJ2 registers based on the temperature T found in the STEMP register and on the coefficients describing the expected behavior of VREF over temperature (in registers PPMC and PPMC2, and available from the PPMCATE and PPMC2ATE locations loaded from the OTP memory after reset). The formula applied for the gain adjust settings is:

$$GAIN\_ADJ = 16385 + \frac{PPMC \cdot T}{2^{14}} + \frac{PPMC2 \cdot T^2}{2^{23}}$$

This operation mode compensates for the expected variations of VREF over temperature. In this operation mode, system factors still influence the meter's accuracy over temperature. These factors include the current sensors, their signal conditioning circuits, and the resistive dividers for voltage. If these system factors can be characterized, the resulting behavior of the system over temperature can be compensated with new values for PPM and PPMC2 that are a combination of the VREF characteristics (as stored in PPMCATE and PPMCATE2) and the sensor temperature characteristics. If a linear and quadratic compensation is sufficient, the host can load the new compensation values into the PPMC and PPMC2 registers and have the CE code operate in internal temperature compensation mode.

#### Note: If the host does not set up PPMC and PPMC2, it can void the accuracy of the MAX71020. The minimum setup is to copy PPMCATE to PPMC and PPMC2ATE to PPMC2. This sets up the standard digital temperature compensation for VREF.

If compensation with cubic and higher coefficients is required, the calculation of the necessary GAIN\_ADJ values should be implemented in the host. In this case, the host should set the EXT\_TEMP bit in the CECONFIG register to 1 and control the GAIN\_ADJ registers directly. It is possible to apply individual compensation schemes for the voltage (GAIN\_ADJ0) and current (GAIN\_ADJ1, GAINADJ2) channels.

## **Single-Chip Electricity Meter AFE**

#### **Crystal Oscillator**

The oscillator drives an AT cut microprocessor crystal at a frequency of 9.8304MHz. Board layouts with minimum capacitance from XIN to XOUT require less current. Good layouts have XIN and XOUT shielded from each other and from digital signals.



Since the oscillator is self-biasing, an external resistor must not be connected across the crystal.

#### Meter Calibration

Once the MAX71020 energy meter device has been installed in a meter system, it must be calibrated. A complete calibration includes the following:

- Establishment of the reference temperature (e.g., typically 22°C).
- Calibration of the metrology section, i.e., calibration for tolerances of the current sensors, voltage-dividers, and signal conditioning components as well as of the internal reference voltage (VREF) at the reference temperature (e.g., typically 22°C).

The metrology section can be calibrated using the gain and phase adjustment factors accessible to the CE. The gain adjustment is used to compensate for tolerances of components used for signal conditioning, especially the resistive components. Phase adjustment is provided to compensate for phase shifts introduced by the current sensors or by the effects of reactive power supplies. The MAX71020 supports common industry-standard calibration techniques, such as single-point (energy-only) and multipoint (energy,  $V_{RMS}$ ,  $I_{RMS}$ ).

The load engine seeds some CE and hardware control registers with default values required for proper operation of the CE code, but not the calibration registers (CAL\_IA, CAL\_VA, etc., and PHADJ\_A and PHADJ\_B) and a variety of other registers that need to change dynamically. The default values shown in Table 7 apply to ideal sensors and an ideal trim value of VREF. Calibration yields non-default values for the calibration registers. Storage of the calibration registers should be implemented in the host, and on power-up or after reset, the host must write the stored values into the calibration registers of the MAX71020. If the meter constant or any other of the parameters listed in Table 7 had been changed from default, the host must also update these values on power-up and after reset.

<u>Table 7</u> lists in the column LOADED BY the source that is used to seed the value. Host means that the host controller is responsible for loading the value into the CE RAM upon reset or power-up. The host must ensure that the registers labeled "Host" are maintained, preserved, and checked whenever the MAX71020 reports a reset or supply power event in its M\_STAT register. LE means that the Load Engine provides the data for the register. The registers labeled R in the R/W column need not be seeded with values ( — in LOADED BY column).

### **Host Controller Interface**

#### **Register Map**

NAME	BYTE ADDRESS	R/W	DEFAULT VALUE	DESCRIPTION	LOADED BY
CAL_I0	0x010	R/W	0x0000 4000	Calibration coefficient for current channel A. Default = unity gain	Host
CAL_V0	0x011	R/W	0x0000 4000	Calibration coefficient for voltage channel A.	Host
PHADJ_0	0x012	R/W	0x0000 0000	Phase adjust coefficient for channel A. Default = no phase adjust.	Host
CAL_I1	0x013	R/W	0x0000 4000	Calibration coefficient for current channel B.	Host
CAL_V1	0x014	R/W	0x0000 4000	Calibration coefficient for voltage channel B.	Host
PHADJ_1	0x015	R/W	0x000 0000	Phase adjust coefficient for channel B.	Host
DEGSCALE	0x01A	R/W	0x0000 6A8F	Internal constant	LE

#### Table 7. Register Map

# **Single-Chip Electricity Meter AFE**

NAME	BYTE ADDRESS	R/W	DEFAULT VALUE		LOADED BY				
PPMC	0x01B	R/W	0x0000 0000	Linea defau PPMC	Linear coefficient for temperature compensation. A default coefficient can be established by copying PPMCATE into PPMC.				
PPMC2	0x01C	R/W	0x0000 0000	Quad A def PPMC	ratic coefficient for ault coefficient can C2ATE into PPMC2.	temperature compensation. be obtained by copying	Host		
PPMCATE	0x01D	R/W	Varies	Linea	r coefficient for temp	perature compensation from ATE	LE		
PPMC2ATE	0x01E	R/W	Varies	Quad from <i>J</i>	Quadratic coefficient for temperature compensation from ATE				
				Confi	Configuration register for CE operation				
			0x0030 3301	BIT	NAME	DESCRIPTION			
CECONFIG		R/W		0	PULSE_SLOW	Reduces pulse output rate by a factor of 64. Must not be used with PULSE_FAST.			
				1	PULSE_FAST	Increases pulse output rate by a factor of 16. Must not be used with PULSE_SLOW.	-		
				7:2	Reserved				
	0x020			19:8	SAG_CNT	Number of consecutive samples below SAG_THR before sag event is declared.	Host		
				20	SAG_INT	Enables sag detect output on YPULSE			
				21	EDGE_INT	Enables zero-crossing output on XPULSE			
				22	EXT_TEMP	External control of GAIN_ ADJn if set			
				23	PULSE_SELECT	Selector for Wh and VARh pulse generators (0 = phase A, 1 = phase B)			
				24	CREEP	1 if meter is in creep mode			
WRATE	0x021	R/W	0x0000 441E	Sets t Pulse	he meter constant Generation sectior	for pulse outputs. See the n.	Host		
KVAR	0x022	R/W	0x0000 192C	Intern	al scaling factor fo	r VARh measurements.	LE		
SUM_PRE	0x023	R/W	0x0000 09D8	= 252 by the	20. For information of code.	only. This location is not used	Host		
SAG_THR	0x024	R/W	0x016D 2490	Voltag and C	ge threshold for sag <i>Control</i> section	g warnings. See the CE Status	Host		
QUANT_V0	0x025	R/W	0x0000 0000	Trunc	ation/noise compe	nsation for voltage in phase A	Host		

### Table 7. Register Map (continued)

# **Single-Chip Electricity Meter AFE**

NAME	BYTE ADDRESS	R/W	DEFAULT VALUE	DESCRIPTION			LOADED BY	
QUANT_I0	0x026	R/W	0x0000 0000	Trunca	ation/noi	se compensation for current in phase A	Host	
QUANT_0	0x027	R/W	0x0000 0000	Trunca	tion/nois	e compensation for real power in phase A	Host	
QUANT_VAR0	0x028	R/W	0x0000 0000	Trunca phase	Truncation/noise compensation for reactive power in phase A			
QUANT_V0	0x029	R/W	0x0000 0000	Trunca	ation/noi	se compensation for voltage in phase B	Host	
QUANT_I0	0x02A	R/W	0x0000 0000	Trunca	ation/noi	se compensation for current in phase B	Host	
QUANT_0	0x02B	R/W	0x0000 0000	Trunca	Truncation/noise compensation for real power in phase B			
QUANT_VAR0	0x02C	R/W	0x0000 0000	Trunca phase	Truncation/noise compensation for reactive power in phase B			
TEMP22	0x03C	R/W	0x0000 024D	Tempe tempe	Temperature reading at 22°C. Used to calculate temperature deviation from 22°C			
GAINADJ_0	0x040	R/W	0x0000 4000	Adjust tempe	Adjusts the amplitude for voltage inputs VA and VB for temperature compensation. Default = unity gain.			
GAINADJ_1	0x041	R/W	0x0000 4000	Adjust unity g	Adjusts the amplitude for current input IA. Default = unity gain.			
GAINADJ_2	0x042	R/W	0x0000 4000	Adjust unity g	Adjusts the amplitude for current input IB. Default = unity gain.			
APULSEW	0x044	R	—				—	
WPULSE_CTR	0x045	R	—	Pulse	counter	for Wh (real power)	—	
WPULSE_FRAC	0x046	R		Pulse	generat	or numerator for Wh (real power)	—	
WSUM_ACCUM	0x047	R	—	Pulse g	Pulse generator rollover accumulator for Wh (real power)			
AVPULSER	0x048	R	—					
VPULSE_CTR	0x049	R	—	Pulse	Pulse counter for Wh (real power)			
VPULSE_FRAC	0x04A	R	—	Pulse	generat	or numerator for Wh (real power)	—	
VSUM_ACCUM	0x04B	R	—	Pulse g	generato	or rollover accumulator for Wh (real power)		
	0x04C0x07F		—	Used I	by CE fo	or internal variables	—	
				Status	of the C	Compute Engine	-	
				BIT		DESCRIPTION	-	
				0		Sag status for voltage phase A. Automatically clears when the voltage rises above SAG_THR.		
CESTATUS	0x080	R	_	1		Sag status for voltage phase B. Automatically clears when the voltage rises above SAG_THR.		
				2	_		]	
				3	_	Square wave at exact line frequency	]	
				31:4	_			
TEMP_X	0x081	R		Tempe	erature o	deviation from TEMP22		
FREQ_X	0x082	R		Funda	mental I	ine frequency in units of (2520.6 x 2 <sup>-32</sup> ) Hz	_	
MAINEDGE_X	0x083	R		Numbe during	er of vol the pre	tage zero crossings of either direction vious accumulation interval	_	

### Table 7. Register Map (continued)

Maxim Integrated

# **Single-Chip Electricity Meter AFE**

NAME	BYTE ADDRESS	R/W	DEFAULT VALUE	DESCRIPTION	LOADED BY
WSUM_X	0x084	R		Signed sum of real energy (Wh) from both wattmeter elements for the previous accumulation interval	
WOSUM_X	0x085	R		Signed sum of real energy (Wh) from wattmeter element A	—
W1SUM_X	0x086	R	_	Signed sum of real energy (Wh) from wattmeter element B	
VARSUM_X	0x088	R	_	Signed sum of reactive energy (VARh) from both wattmeter elements for the previous accumulation interval	
VAR0SUM_X	0x089	R	_	Signed sum of reactive energy (VARh) from wattmeter element A	
VAR1SUM_X	0x08A	R	_	Signed sum of reactive energy (VARh) from wattmeter element B	
IOSQSUM_X	0x08C	R		Sum of squared samples from current sensor in phase A	_
I1SQSUM_X	0x08D	R		Sum of squared samples from current sensor in phase B	—
V0SQSUM_X	0x090	R	_	Sum of squared samples from voltage sensor in phase A	—
V1SQSUM_X	0x091	R	_	Sum of squared samples from voltage sensor in phase B	_
I0SQRES_X	0x096	R	—	Residual current from current sensor in phase A	—
I1SQRES_X	0x097	R	—	Residual current from current sensor in phase A	—
I0_RAW	0x100	R	_	Most recent result of ADC conversion for current phase A	—
V0_RAW	0x101	R		Most recent result of ADC conversion for voltage phase A	—
I1_RAW	0x102	R	—	Most recent result of ADC conversion for current phase B	_
V1_RAW	0x103	R		Most recent result of ADC conversion for voltage phase A	—

### Table 7. Register Map (continued)

### Table 8. Hardware Control Register Map

NAME	BYTE ADDRESS	R/W	DEFAULT VALUE*			DESCRIPTION			
				Contains identifying information for the device. Loaded by the LE.					
	0x301			BIT	NAME	DESCRIPTION			
			0x0000 1100	7:0	Reserved	—			
DEVICEID				15:8	VERSION	Version index. Currently, 0:	x12 is defined as die type A0B.		
		R		31:16	CHIP_ID	Family tag and feature tag of the device, currently 0x1001.			
						FAMILY/FEATURE TAG	CE CODE		
						1000	Blank OTP		
						1001	2520 code		
						1002	5k code		
STEMP	0x30A	R	_	Result of the temperature measurement. Only bits 26:16 are significant; all other bits return zero.					
VSENSE	0x30B	R	_	Result other b	of the device its return zer	$V_{V3P3SYS}$ measurement. Or o.	nly bits 23:16 are significant; all		

# **Single-Chip Electricity Meter AFE**

NAME	BYTE ADDRESS	R/W	DEFAULT VALUE*	DESCRIPTION					
				Contai	ns the characteris	stics of the four digital I/O pins.			
				BIT	NAME	DESCRIPTION			
				0	DIO	Reflects logic state on DIO0			
				1	DI1	Reflects logic state on DIO1			
				2	DI2	Reflects logic state on DIO2			
				3	DI3	Reflects logic state on DIO3			
				7:4	Reserved	—			
				8	D_OD0	Configures DIO0 as open drain if configured as output			
				9	D_OD1	Configures DIO1 as open drain if configured as output			
				10	D_OD2	Configures DIO2 as open drain if configured as output			
IOCFG				11	D_OD3	Configures DIO3 as open drain if configured as output			
			0x0000 0F00	15:12	Reserved	—			
	0x30C	R/W		17:16	DO	Configures DIO0. 00: High-Z 01: WPULSE 10: Logic 1 11: Logic 0			
				19:18	D1	Configures DIO1. 00: High-Z 01: VPULSE 10: Logic 1 11: Logic 0			
				21:20	D2	Configures DIO2. 00: High-Z 01: XPULSE 10: XFER_BUSY 11: Logic 0			
				23:22	D3	Configures DIO3. 00: High-Z 01: YPULSE 10: CE_BUSY 11: Logic			
				31:24	Reserved	—			
				Config	ures hardware as	spects of the AFE.			
				BIT	NAME	DESCRIPTION			
				14:0	Reserved	—			
METER_CFG	0x30D	R/W	0xFF00 0080	15	PLS_INV	Force meter pulses to be positive-going rather than negative-going			
				23:16	Reserved	—			
				31:24	PLS_MAXWID	Determines the maximum width of a meter pulse			

### Table 8. Hardware Control Register Map (continued)

# **Single-Chip Electricity Meter AFE**

NAME	BYTE ADDRESS	R/W	DEFAULT VALUE*			DESCRIPTION
				Interrup	ot configuration r	egister: configure the behavior of the INTZ pin.
				BIT	NAME	DESCRIPTION
					0	IE_WPULSE
					1	IE_VPULSE
				2	IE_YPULSE	Enables an interrupt to occur on the leading edge of YPULSE
	0x30F	R/W	0x0000 8000	3	IE_XPULSE	Enables an interrupt to occur on the leading edge of XPULSE
				4	IE_XDATA	Enables an interrupt to occur at the conclusion of the accumulation interval, indicating that fresh data is available
INT_CFG				5	IE_CEBUSY	Enables an interrupt to occur when the CE cycles is complete
				6	Reserved	_
				7	IE_VSTAT	Enables an interrupt to occur when the VSYS status changes
				11:8	INT_POL	Interrupt polarity for the PULSE edges. The default polarity is falling edge. INT_POL[3]=1: Interrupt on rising edge of YPULSE INT_POL[2]=1: Interrupt on rising edge of XPULSE INT_POL[1]=1: Interrupt on rising edge of VPULSE INT_POL[0]=1: Interrupt on rising edge of WPULSE
				14:12	Reserved	—
				15	D_ODINTZ	Enable open-drain on the INTZ output. By default, the pin is configured as a CMOS totem-pole output.
				31:16	Reserved	_

### Table 8. Hardware Control Register Map (continued)

# **Single-Chip Electricity Meter AFE**

NAME	BYTE ADDRESS	R/W	DEFAULT VALUE*			DESCRIPTION
				Reflect automa	s the status of se atically cleared at	everal asynchronous events in the AFE. Bits are iter the host controller reads M_STAT.
				BIT	NAME	DESCRIPTION
				0	F_WPULSE	Set on start of WPULSE
				1	F VPULSE	Set on start of VPULSE
				2	F_XPULSE	Set on start of XPULSE
				3	F_YPULSE	Set on start of YPULSE
				4	F_XDATA	Set when data available
				5	F_CEBUSY	Set at end of CE code pass
				6	Reserved	_
M STAT	0v310	D	0x0100	7	F_VSTAT	Set when VSYS status changes
IVI_STAT	0,310	п	0100	8	F_RESET	Set following AFE reset
				15:9	Reserved	_
				16	F_WPULSE	Copy of bit 0
				17	F_VPULSE	Copy of bit 1
				18	F_XPULSE	Copy of bit 2
				19	F_YPULSE	Copy of bit 3
				20	F_XDATA	Copy of bit 4
				21	F_CEBUSY	Copy of bit 5
				23:22	Reserved	—
				24	F_RESET	Copy of bit 8
				31:25	Reserved	—
				Backup	of M_STAT – up	odated when M_STAT is read. If M_STAT_B is different
				change	_STAT, it signals e detect).	to the host that something has changed (status
				BIT	NAME	DESCRIPTION
				0	FB_WPULSE	Set on start of WPULSE
				1	FB_VPULSE	Set on start of VPULSE
				2	FB_XPULSE	Set on start of XPULSE
				3	FB_YPULSE	Set on start of YPULSE
				4	FB_XDATA	Set when data available
				5	FB_CEBUSY	Set at end of CE code pass
	0.011		0x0000	7:6	Reserved	
M_STAT_B	0x311	К	0000	8	FB_RESET	Set following AFE reset
				15:9	Reserved	_
				16	FB_WPULSE	Copy of bit 0
				17	FB_VPULSE	Copy of bit 1
				18	FB_XPULSE	Copy of bit 2
				19	FB_YPULSE	Copy of bit 3
				20	FB_XDATA	Copy of bit 4
				21	FB_CEBUSY	Copy of bit 5
				23:22	Reserved	
				24	FB_RESET	Copy of bit 8
				31:25	Reserved	

### Table 8. Hardware Control Register Map (continued)

# **Single-Chip Electricity Meter AFE**

NAME	BYTE ADDRESS	R/W	DEFAULT VALUE*			DESCRIPTION		
VSTAT	0x312	R	_	AFE Supply Voltage Status. Bits 1:0 reflect system power status: 00: System power-OK: $V_{V3P3A} > 3.0V$ 01: System power-low: $2.8V < V_{V3P3A} < 3.0V$ 11: System power-fail: $V_{V3P3A} < 2.8V$				
RESET	0x322	WO		Write 0x8100 0000 to this register to reset the AFE.				
			Configute the LE.	Configures aspects of the temperature measurement subsystem. Loaded by the LE.				
		R/W	BIT         NAME         DESCR           1:0         Reserved         —           0x0000         3:2         TEMP_PER         Sets the period between ter 01: Measure every accumu 10: Continuous measureme Other values disable autom           4         TEMP_SYS         When set, Vy3P3SYS is mea measurement cycle           31:5         Reserved         —           0x0000         Write 0x8000 0000 to start a temperature conversion c	BIT	NAME	DESCRIPTION		
				1:0	Reserved	_		
TEMP_CNF	0x323			3:2	TEMP_PER	<ul><li>Sets the period between temperature measurements.</li><li>01: Measure every accumulation cycle</li><li>10: Continuous measurement</li><li>Other values disable automatic updates.</li></ul>		
				4	TEMP_SYS	When set, $V_{\mbox{V3P3SYS}}$ is measured at every temperature measurement cycle		
TEMP_START	0x324	R/W	0x0000 0000	Write 0: comple	x8000 0000 to st ete, the AFE clea	art a temperature conversion cycle. When conversion is rs bit 31 and returns the register to zero.		
SPI_SAFE	0x325	R/W	0x0000 0000	Write 0 locked registe operati	x8000 0000 to t , no read or writ r. Clearing this r on.	his word to lock the SPI port. When the SPI port is e operations are possible except to the SPI_SAFE egister to zero disables the SPI lock and restores normal		
				Enable	s aspects of the	AFE.		
				BIT	NAME	DESCRIPTION		
METER_EN	0x326	R/W	0x0000 0000	0	ADC_E	Enable ADC and VREF buffer. Must be set by host following initialization.		
				1	CE_E	Enable CE. Must be set by host following initialization.		
				31:2	Reserved	_		

### Table 8. Hardware Control Register Map (continued)

\*Default values given for standard CE code (2520 sample frequency, gain = 9).

#### **CE Interface Description**

The CE reads the ADC and stores its results in the 1KB block at 0x000. Since all CE operations are 32 bits wide, the CE data memory occupies the first 256 32-bit locations, from 0x000 to 0x0FF.

**Note:** The CE interface described in the data sheet is a description of the released CE code. Contact your representative or Maxim Integrated technical support for the latest information on alternate CE codes.

#### CE Data Format

All CE words are 4 bytes. Unless specified otherwise, they are in 32-bit two's complement format (-1 = 0xFFFFFFF). Calibration parameters are copied to CE data memory by the host controller before enabling the CE. Internal variables are used in internal CE calculations. Input variables allow the MPU to control the behavior of the CE code.

# **Single-Chip Electricity Meter AFE**

		INPUTS USED FOR ENERGY/CURRENT CALCULATION						
EQU	(WSUM/VARSUM)	W0SUM/ VAR0SUM	W1SUM/ VAR1SUM	IOSQ SUM	I1SQ SUM			
0	VA IA – 1 element, 2W 1ø	VA x IA	VA x IB	IA	—			
1*	VA x (IA-IB)/2 – 1 element, 3W 1ø	VA x (IA-IB)/2		IA-IB	IB			
2*	VA x IA + VB x IB– 2 element, 3W 1ø	VA x IA	VB x IB	IA	IB			

### Table 9. CE EQU Equations and Element Input Mapping

\*Not supported by standard CE codes.

### Table 10. CE Raw Data Access Locations

PIN	REGISTER
IA	0x100
VA	0x101
IB	0x102
VB	0x103

#### Constants

Constants used in the CE Data Memory tables are:

- f<sub>0</sub> is the fundamental frequency of the mains phases.
- I<sub>MAX</sub> is the external RMS current corresponding to the maximum allowed voltage on the current inputs. For the IB input, this is 250mV peak (176.8mV<sub>RMS</sub>). In the MAX71020, IA normally has a preamplifier enabled on the IA inputs, so I<sub>MAX</sub> needs to be adjusted to 27.78mV peak (19.64mV<sub>RMS</sub>) for the IAP-IAN inputs. For a 250 $\mu$ Ω shunt resistor, I<sub>MAX</sub> becomes 78A (19.64mV<sub>RMS</sub>/250 $\mu$ Ω = 78.57A) for IA, and 707A (176.8mV<sub>RMS</sub>/250 $\mu$ Ω = 707.2A<sub>RMS</sub>) for IB.
- V<sub>MAX</sub> is the external RMS voltage corresponding to 250mV peak at the VA and VB inputs.
- N<sub>ACC</sub>, the accumulation count for energy measurements (typically 2520).
- The duration of the accumulation interval for energy measurements is N<sub>ACC</sub>/F<sub>S</sub> = 2520/2,520.6  $\approx$  1s.
- X is a gain constant of the pulse generators. Its value is determined by PULSE\_FAST and PULSE\_SLOW.
- Voltage LSB (for sag threshold) = V<sub>MAX</sub> x 7.879810 9V.

The system constants  $I_{MAX}$  and  $V_{MAX}$  are used by the host controller to convert internal digital quantities (as used by the CE) to external, real-world metering quantities. Their values are determined by the scaling of the voltage

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and current sensors used in an actual meter. The LSB values used in this document relate digital quantities at the CE or MPU interface to external meter input quantities. For example, if a SAG threshold of  $80V_{RMS}$  is desired at the meter input, the digital value that should be programmed into SAG\_THR (register 0x024) would be  $80V_{RMS} \times SQRT(2)/SAG_THR_{LSB}$ , where SAG\_THR\_LSB is the LSB value in the description of SAG\_THR (see Table 12).

#### Environment

Default settings are assumed to be  $V_{MAX}$  = 600V,  $I_{MAX}$  = 707A, and kH = 1.

#### CE Calculations

In <u>Table 9</u>, the Load Engine selects the desired equation by writing to the METER\_CFG register.

#### CE Front-End Data (Raw Data)

Access to the raw data provided by the AFE is possible by reading registers 0x100-0x003 as shown in <u>Table 10</u>.

#### **CE Status and Control**

The CE Status Word, CESTATUS, is useful for generating early warnings to the host controller (Table 7). It contains sag warnings for phase A and B, as well as F0, the derived clock operating at the line frequency. The host controller can read the CE status word at every CE\_BUSY interrupt.

CESTATUS provides information about the status of voltage and input AC signal frequency, which are useful for generating an early power-fail warning to initiate necessary data storage. CESTATUS represents the status flags for the preceding CE code pass (CE\_BUSY interrupt). The significance of the bits in CESTATUS is shown in <u>Table 7</u>. The CE is initialized by the host controller using CECONFIG (<u>Table 7</u>). This register contains the SAG\_CNT, PULSE\_SLOW, and PULSE\_FAST fields. The CECONFIG bit definitions are given in <u>Table 7</u>. When the SAG\_INT bit (register 0x020[20]) is set to 1, a sag event generates

## **Single-Chip Electricity Meter AFE**

#### Table 11. CESTATUS Register

CE ADDRESS	NAME	DESCRIPTION
0x80	CESTATUS	See the description of CESTATUS bits in Table 7

### Table 12. Sag Threshold and Gain Adjust Control

CE ADDRESS	NAME	DEFAULT	DESCRIPTION	
0x24	SAG_THR	2.39 x 10 <sup>7</sup>	The voltage threshold for sag warnings. The default value is equivalent to 113Vpk or 80V <sub>RMS</sub> if V <sub>MAX</sub> = 600V <sub>RMS</sub> . üüü $= \frac{V_{RMS} \times \sqrt{2}}{V_{MAX} \times 7.8798 \times 10^{-9}}$	
0x40	GAIN_ADJ0	16384	This register scales the voltage measurement channels VA and VB. The default value of 16384 is equivalent to unity gain (1.000).	
0x41	GAIN_ADJ1	16384	This register scales the IA current channel for Phase A. The default value of 16384 is equivalent to unity gain (1.000).	
0x42	GAIN_ADJ2	16384	This register scales the IB current channel for Phase B. The default value of 16384 is equivalent to unity gain (1.000).	

### Table 13. CE Transfer Variables

CE ADDRESS	NAME	DESCRIPTION	
0x84	WSUM_X	The signed sum: W0SUM_X + W1SUM_X. Not used for EQU[2:0] = 0 (register $0x30D[14:12]$ ) and EQU[2:0] = 1.	
0x85	WOSUM_X	The sum of Wh samples from each wattmeter element.	
0x86	W1SUM_X	$LSB_{W} = 6.08040 \times 10^{-13} \times V_{MAX} \times I_{MAX} Wh$	
0x88	VARSUM_X	The signed sum: VAR0SUM_X + VAR1SUM_X. Not used for EQU[2:0] = 0 and EQU[2:0] = 1.	
0x89	VAR0SUM_X	The sum of VARh samples from each wattmeter element.	
0x8A	VAR1SUM_X	$LSB_{W} = 6.08040 \times 10^{-13} \times V_{MAX} \times I_{MAX} \text{ VARh}$	

a transition on the YPULSE output. The CE controls the pulse rate based on WSUM\_X (register 0x084) and VARSUM\_X (register 0x088).

#### **CE Transfer Variables**

When the host controller receives the INTZ interrupt, it knows that fresh data is available in the transfer variables. They remain constant throughout each accumulation interval. In this data sheet, the names of CE transfer variables always end with "\_X". The transfer variables can be categorized as:

- Fundamental energy measurement variables
- Instantaneous (RMS) values
- Other measurement parameters

#### Fundamental Energy Measurement Variables

Table 13 describes each transfer variable for fundamental energy measurement. All variables are signed 32-bit integers. Accumulated variables such as WSUM are internally scaled so that internal values are no more than 50% of the full-scale range when the integration time is

## **Single-Chip Electricity Meter AFE**

one second. Additionally, the hardware does not permit output values to fold back upon overflow.

WSUM\_X (register 0x084) and VARSUM\_X (register 0x088) are the signed sum of Phase-A and Phase-B Wh or VARh values according to the metering equation implemented by the CE code. WxSUM\_X (x = 0 or 1, registers 0x085 and 0x086) is the watt-hour value accumulated for phase x in the last accumulation interval and can be computed based on the specified LSB value.

#### Instantaneous Energy Measurement Variables

I\_SQSUM\_X and V\_SQSUM (see <u>Table 14</u>) are the sum of the squared current and voltage samples acquired during the last accumulation interval.

The RMS values can be computed by the host controller from the squared current and voltage samples as follows:



Other

Other transfer variables include those available for frequency and those reflecting the count of the zerocrossings of the mains voltage. These transfer variables are listed in Table 15.

MAINEDGE\_X (register 0x083) reflects the number of half-cycles accounted for in the last accumulated interval for the voltage signal. MAINEDGE\_X is useful for implementing a real-time clock based on the input AC signal.

#### **Pulse Generation**

Table 16 describes the CE pulse generation parameters. The combination of the CECONFIG:PULSE\_SLOW and CECONFIG:PULSE\_FAST bits (register 0x020[0:1]) controls the speed of the pulse generator. The default zero values of these configuration bits maintain the original pulse rate given by the Kh equation, described below.

WRATE (register 0x021) controls the number of pulses that are generated per measured Wh and VARh. The lower WRATE is, the slower the pulse rate for the measured energy quantity; or conversely, the greater the measured energy per pulse. By default, the pulse generators take their input from the WOSUM\_X (register 0x085) and VAR0SUM\_X (register 0x089) result registers.

CE ADDRESS	NAME	DESCRIPTION	CONFIGURATION
0x8C	IOSQSUM_X	The sum of squared current samples from each element.	
0x8D	I1SQSUM_X	$LSD_{I} = 6.08040 \times 10^{-10}$ MAX2 Activity When EQU = 1, I0SQSUM_X is based on IA and IB.	Figure 8
0x90	V0SQSUM_X	The sum of squared voltage samples from each element.	Ŭ
0x91 <sup>+</sup>	V1SQSUM_X	LSB <sub>v</sub> = 6.08040 x 10 <sup>-13</sup> VMAX <sup>2</sup> V <sup>2</sup> h	

#### Table 14. CE Energy Measurement Variables

### Table 15. Other Transfer Variables

CE ADDRESS	NAME	DESCRIPTION	
0x82	FREQ_X	Fundamental frequency: LSB = $\frac{2520.6\text{Hz}}{2^{32}} \approx 0.509 \times 10^{-6}$	
0x83	MAINEDGE_X	The number of edge crossings of the selected voltage in the previous accumulation interval. Edge crossings are either direction and are debounced.	

### **Single-Chip Electricity Meter AFE**

The meter constant Kh is derived from WRATE and represents the amount of energy measured for each pulse. If Kh = 1Wh/pulse and 120V and 30A is applied in-phase to the meter, the meter will produce one pulse per second (120V and 30A results in a load of 3600W, or put another way, energy consumption of one watt-hour per second). If the load is 240V at 150A, 10 pulses per second are generated. To compute the WRATE value, see <u>Table 16</u>.

The maximum pulse rate is 7.56kHz.

See the <u>VPULSE and WPULSE</u> section for details on how to adjust the timing of the output pulses. The maximum time jitter is 1/6 of the multiplexer cycle period (nominally 67 $\mu$ s) and is independent of the number of pulses measured. Thus, if the pulse generator is monitored for one second, the peak jitter is 67ppm. After 10s, the peak jitter is 6.7ppm. The average jitter is always zero. If it is attempted to drive either pulse generator faster than its maximum rate, it simply outputs at its maximum rate without exhibiting any rollover characteristics. The actual pulse rate, using WSUM as an example, is:

$$RATE = \frac{WRATE \times WSUM \times f_S \times X}{2^{46}}Hz$$

where  $f_S$  = sampling frequency (2520.6Hz), X = pulse speed factor derived from the CE variables PULSE\_SLOW (register 0x020[0]) and PULSE\_FAST (register 0x020[1]).

#### Other CE Parameters

Table 17 shows the CE parameters used for suppression of noise due to scaling and truncation effects.

#### **CE** Calibration Parameters

Table 18 lists the parameters that are typically entered to effect calibration of meter accuracy.

#### **CE Flow Diagrams**

Figure 10 to Figure 12 show the data flow through the CE in simplified form. Functions not shown include delay compensation, sag detection, scaling, and the processing of meter equations.

CE ADDRESS	NAME	DEFAULT	DESCRIPTION	
0x21	WRATE	547	$\label{eq:Kh} \begin{split} Kh = & \frac{K \times V_{MAX} \times I_{MAX}}{\ddot{u}\ddot{u}\ddot{u}\ddot{u}\ddot{u}\ddot{u}\ddot{u}\ddot{u}} \times \times} \ Wh/pulse \end{split}$ where: $K = 42.7868 \\ The default value yields 1.0 Wh/pulse for V_{MAX} = 600V \ and \ I_{MAX} = 208A. \ The maximum value for WRATE is 32,768 (215). \end{split}$	
0x22	KVAR	6444	Scale factor for VAR measurement	
0x45	WPULSE_CTR	0	WPULSE counter	
0x46	WPULSE_FRAC	0	Unsigned numerator, containing a fraction of a pulse. The value in this register always counts up towards the next pulse.	
0x47	WSUM_ACCUM	0	Rollover accumulator for WPULSE	
0x49	VPULSE_CTR	0	VPULSE counter	
0x4A	VPULSE_FRAC	0	Unsigned numerator, containing a fraction of a pulse. The value in this register always counts up towards the next pulse.	
0x4B	VSUM_ACCUM	0	Rollover accumulator for VPULSE	

#### Table 16. CE Pulse Generation Parameters

# **Single-Chip Electricity Meter AFE**

CE ADDRESS	NAME	DEFAULT	DESCRIPTION		
0x25	QUANT_VA	0			
0x26	QUANT_IA	0	Compensation factors for truncation and noise in voltage, current, real energy, and		
0x27	QUANT_A	0	reactive energy for phase A.		
0x28	QUANT_VARA	0	1		
0x29	QUANT_VB	0			
0x2A	QUANT_IB	0	Compensation factors for truncation and noise in voltage, current, real energy, and		
0x2B	QUANT_B	0	reactive energy for phase B.		
0x2C	QUANT_VARB	0			
QL	$QUANT_Ix_LSB = 3.28866 \times 10^{-13} \times I_{MAX}^2 (Amps^2)$				
$QUANT_Wx_LSB = 6.73518 \times 10^{-10} \times V_{MAX} \times I_{MAX} (Watts)$					
QL	JANT_VARx_LSB =	6.73518×10	$^{-10} \times V_{MAX} \times I_{MAX}$ (Vars)		

Table 17. CE Parameters for Noise Suppression and Code Version

Table 1	8. (	CE	Calibration	<b>Parameters</b>
---------	------	----	-------------	-------------------

CE ADDRESS	NAME	DEFAULT	DESCRIPTION	
0x10	CAL_IA	16384	These constants control the gain of their respective channels. The nominal	
0x11	CAL_VA	16384	value for each parameter is $2^{14} = 16384$ . The gain of each channel is directly	
0x13	CAL_IB	16384	proportional to its CAL parameter. Thus, if the gain of a channel is 1% slow, CAL	
0x14	CAL_VB	16384	should be increased by 1%.	
0x12	PHADJ_A	0	These constants control the CT phase compensation. Compensation does not occur when PHADJ_X = 0. As PHADJ_X is increased, more compensation (lag) is introduced. The range is $\pm 215 - 1$ . If it is desired to delay the current by the angle $\Phi$ , the equations are:	
0x15	PHADJ_B	0	PHADJ_X = $2^{20} \frac{0.02229 \times TAN\Phi}{0.1487 \cdot 0.0131 \times TAN\Phi}$ at 60Hz PHADJ_X = $2^{20} \frac{0.0155 \times TAN\Phi}{0.1241 \cdot 0.009695 \times TAN\Phi}$ at 50Hz	

# **Single-Chip Electricity Meter AFE**



Figure 10. CE Data Flow (Multiplexer and ADC)



Figure 11. CE Data Flow (Scaling, Gain Control, Intermediate Variables)





Figure 12. CE Data Flow (Squaring and Summation Stages)

### **Ordering Information**

PART	ACCURACY (%)	PIN-PACKAGE
MAX71020AEUI+	0.5	28 TSSOP
MAX71020AEUI+R	0.5	28 TSSOP

**Note:** All devices are specified over the -40°C to +105°C operating temperature range.

+Denotes a lead(Pb)-free/RoHS-compliant package.

R = Tape and reel.

### **Package Information**

For the latest package outline information and land patterns (footprints), go to <u>www.maximintegrated.com/packages</u>. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE	PACKAGE	OUTLINE	LAND
TYPE	CODE	NO.	PATTERN NO.
28 TSSOP	U28+1	<u>21-0066</u>	<u>90-0171</u>

# **Single-Chip Electricity Meter AFE**

### **Revision History**

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	7/12	Initial release	
1	1/13	Updated the <i>Electrical Characteristics</i> table, <i>Functional Diagram</i> , and Table 7; replaced the <i>Reset Sequence</i> section; added a <i>Mechanism</i> description to the <i>Metrology Temperature Compensation</i> section; added new Table 8; removed original Tables 11, 12, and 13; updated Figures 3, 5–12	All



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